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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/814,682	03/31/2004	Wen Lin	LIN 13-38	8308
47396	7590 04/20/2005		EXAMINER	
HITT GAINES, PC AGERE SYSTEMS INC.			MALDONADO, JULIO J	
PO BOX 832			ART UNIT PAPER NUMBER	
RICHARDS	RICHARDSON, TX 75083			
			DATE MAILED: 04/20/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)	_N
	10/814,682	LIN ET AL.	(a_{i})
Office Action Summary	Examiner	Art Unit	
	Julio J. Maldonado	2823	
The MAILING DATE of this communication a Period for Reply	appears on the cover sheet wi	th the correspondence addre	9SS
A SHORTENED STATUTORY PERIOD FOR REF THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a - If NO period for reply is specified above, the maximum statutory peri - Failure to reply within the set or extended period for reply will, by sta Any reply received by the Office later than three months after the ma earned patent term adjustment. See 37 CFR 1.704(b).	N. 1.136(a). In no event, however, may a reply within the statutory minimum of third iod will apply and will expire SIX (6) MON tute, cause the application to become AB	eply be timely filed y (30) days will be considered timely. THS from the mailing date of this comm ANDONED (35 U.S.C. § 133).	nunication.
Status			
1) Responsive to communication(s) filed on			
2a) ☐ This action is FINAL . 2b) ☑ T	his action is non-final.		
3) Since this application is in condition for allow closed in accordance with the practice under the condition of the cond	·	•	nerits is
Disposition of Claims			
4) ☐ Claim(s) 21-27 and 37-39 is/are pending in 4a) Of the above claim(s) is/are withd 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 21-27 and 37-39 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and	Irawn from consideration.		
Application Papers			
9) The specification is objected to by the Exam			
10)☐ The drawing(s) filed on is/are: a)☐ a			
Applicant may not request that any objection to the		` '	4.4044.0
Replacement drawing sheet(s) including the corn 11) The oath or declaration is objected to by the	· =	•	
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority docume 2. Certified copies of the priority docume 3. Copies of the certified copies of the papplication from the International Burnet * See the attached detailed Office action for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplication from the section for a line of the papplica	ents have been received. ents have been received in A riority documents have been eau (PCT Rule 17.2(a)).	pplication No received in this National St	age
Attachment(s)			
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948)		Summary (PTO-413) s)/Mail Date	
Information Disclosure Statement(s) (PTO-1449 or PTO/SB/0 Paper No(s)/Mail Date 20040331.		nformal Patent Application (PTO-1	52)
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DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1 are rejected under 35 U.S.C. 103(a) as being unpatentable over Bevk et al. (U.S. 5,500,391).

In reference to claims 21-23, 37 and 38, Bevk et al. (Figs.2 and 6) teach a MOS device including a co-doped germanium buried layer (34) located over a doped substrate (10); a doped epitaxial layer (30) located over the co-doped germanium buried layer (34); and transistors located over the doped epitaxial layer (30), wherein said dopant is boron and wherein said germanium layer (34) is used to control the diffusion of said dopant (column 1, line 53 – column 4, line 30).

Bevk et al. fail to expressly teach wherein said MOS device further includes interconnects located within interlevel dielectric layers located over the transistors, which connect the transistors to form an operational integrated circuit. However, it is well-known in the art directed to MOS devices that these devices further include interconnects located within interlevel dielectric layers located over the transistors, which connect the transistors to form an operational integrated circuit as evidenced, for example, by Schwabe to U.S. 4,462,149 (column 2, line 62 – column 3, line 16), Murakami to U.S. 4,819,043 (Fig.3M, column 4, lines 26 – 47) and Liu to U.S. 5,476,903

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(Fig.8, column 6, lines 9-30). Therefore, it would have been obvious to one of ordinary skill in the at the time the invention was made that to enable the MOS device as disclosed by Bevk et al. to further include interconnects located within interlevel dielectric layers located over the MOS devices of Bevk et al. to arrive at the claimed invention.

In reference to claims 24 and 25, Bevk et al. substantially teach all aspects of the invention but fail to disclose wherein a dopant concentration of the co-doped germanium buried layer ranges from about 1x10¹⁵ atoms/cm³ to about 1x10²⁰ atoms/cm³, a dopant concentration of the doped substrate ranges from about 1x10¹⁴ atoms/cm³ to about 1x10¹⁵ atoms/cm³, and a dopant concentration of the doped epitaxial layer ranges from about 1x10¹⁴ atoms/cm³ to about 1x10¹⁵ atoms/cm³. However, the selection of the selected dope ranges is obvious because it is a matter of determining optimum process condition by routine experimentation with a limited number of species to obtain a desired dopant concentration on the substrate, germanium layer and the epitaxial layer. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to use the above-mentioned dopant concentration to arrive at the claimed invention.

In reference to claims 26 and 27, Bevk et al. substantially teach all aspects of the invention but fail to disclose wherein the co-doped germanium buried layer has a thickness ranging from about 1 μ m to about 10 μ m, and wherein the doped substrate, co-doped germanium buried layer, and the doped epitaxial layer collectively have a thickness ranging from about 2 μ m to about 20 μ m. Notwithstanding, it would have

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been an obvious matter of design choice bounded by well known manufacturing constraints and ascertainable by routine experimentation and optimization to choose these particular dimensions because applicant has not disclosed that the dimensions are for a particular unobvious purpose, produce an unexpected result, or are otherwise critical, and it appears prima facie that the process would possess utility using another dimension. Indeed, it has been held that mere dimensional limitations are prima facie obvious absent a disclosure that the limitations are for a particular unobvious purpose, produce an unexpected result, or are otherwise critical. See, for example, In re Rose, 220 F.2d 459, 105 USPQ 237 (CCPA 1955); In re Rinehart, 531 F.2d 1048, 189 USPQ 143 (CCPA 1976); Gardner v. TEC Systems, Inc., 725 F.2d 1338, 220 USPQ 777 (Fed. Cir. 1984), cert. denied, 469 U.S. 830, 225 USPQ 232 (1984); In re Dailey, 357 F.2d 669, 149 USPQ 47 (CCPA 1966).

Conclusion

- 3. Any inquiry concerning this communication or earlier communications from the examiner should be directed to examiner Julio J. Maldonado whose telephone number is (571) 272-1864. The examiner can normally be reached on Monday through Friday.
- 4. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri, can be reached on (571) 272-1855. The fax number for this group is 703-872-9306 for before final submissions, 703-872-9306 for after final submissions and the customer service number for group 2800 is (703) 306-3329. Updates can be found at http://www.uspto.gov/web/info/2800.htm.

Julio J. Maldonado Patent Examiner Art Unit 2823

Julio J. Maldonado April 15, 2005

George Fourson
Primary Examiner